Welcome to E-XFL.COM

Understanding Embedded - Microprocessors

Embedded microprocessors are specialized computing chips designed to perform specific tasks within an embedded system. Unlike general-purpose microprocessors found in personal computers, embedded microprocessors are tailored for dedicated functions within larger systems, offering optimized performance, efficiency, and reliability. These microprocessors are integral to the operation of countless electronic devices, providing the computational power necessary for controlling processes, handling data, and managing communications.

Applications of Embedded - Microprocessors

Embedded microprocessors are utilized across a broad spectrum of applications, making them indispensable in

Details	
Product Status	Obsolete
Core Processor	PowerPC e300c2
Number of Cores/Bus Width	1 Core, 32-Bit
Speed	266MHz
Co-Processors/DSP	Communications; QUICC Engine, Security; SEC 2.2
RAM Controllers	DDR, DDR2
Graphics Acceleration	No
Display & Interface Controllers	-
Ethernet	10/100Mbps (3)
SATA	-
USB	USB 2.0 (1)
Voltage - I/O	1.8V, 2.5V, 3.3V
Operating Temperature	-40°C ~ 105°C (TA)
Security Features	Cryptography
Package / Case	516-BBGA
Supplier Device Package	516-PBGA (27x27)
Purchase URL	https://www.e-xfl.com/product-detail/nxp-semiconductors/mpc8321eczqaddc

1.1.2 Serial Interfaces

The MPC8323E serial interfaces are as follows:

- Support for one UL2 interface with 31 multi-PHY addresses (MPC8323E and MPC8323 only)
- Support for up to three 10/100 Mbps Ethernet interfaces using MII or RMII
- Support for up to four T1/E1/J1/E3 or DS-3 serial interfaces (TDM)
- Support for dual UART and SPI interfaces and a single I^2C interface

1.2 QUICC Engine Block

The QUICC Engine block is a versatile communications complex that integrates several communications peripheral controllers. It provides on-chip system design for a variety of applications, particularly in communications and networking systems. The QUICC Engine block has the following features:

- One 32-bit RISC controller for flexible support of the communications peripherals
- Serial DMA channel for receive and transmit on all serial channels
- Five universal communication controllers (UCCs) supporting the following protocols and interfaces (not all of them simultaneously):
  - 10/100 Mbps Ethernet/IEEE 802.3® standard
  - IP support for IPv4 and IPv6 packets including TOS, TTL, and header checksum processing
  - ATM protocol through UTOPIA interface (note that the MPC8321 and MPC8321E do not support the UTOPIA interface)
  - HDLC /transparent up to 70-Mbps full-duplex
  - HDLC bus up to 10 Mbps
  - Asynchronous HDLC
  - UART
  - BISYNC up to 2 Mbps
  - QUICC multi-channel controller (QMC) for 64 TDM channels
- One UTOPIA interface (UPC1) supporting 31 multi-PHYs (MPC8323E- and MPC8323-specific)
- Two serial peripheral interfaces (SPI). SPI2 is dedicated to Ethernet PHY management.
- Four TDM interfaces
- Thirteen independent baud rate generators and 19 input clock pins for supplying clocks to UCC serial channels
- Four independent 16-bit timers that can be interconnected as two 32-bit timers

The UCCs are similar to the PowerQUICC II peripherals: SCC (BISYNC, UART, and HDLC bus) and FCC (fast Ethernet, HDLC, transparent, and ATM).

Table 6. Estimated Typical I/O Power Dissipation (continued)

Local bus I/O load = 25 pF 1 pair of clocks	66 MHz, 32 bits	—	—	0.12	W	—
PCI I/O load = 30 pF	66 MHz, 32 bits	—	—	0.057	W	—
QUICC Engine block and other I/Os	UTOPIA 8-bit 31 PHYs	—	—	0.041	W	Multiply by number of interfaces used.
	TDM serial	—	—	0.001	W	
	TDM nibble	—	—	0.004	W	
	HDLC/TRAN serial	—	—	0.003	W	
	HDLC/TRAN nibble	—	—	0.025	W	
	DUART	—	—	0.017	W	
	MIIs	—	—	0.009	W	
	RMII	—	—	0.009	W	
	Ethernet management	—	—	0.002	W	
	USB	—	—	0.001	W	
	SPI	—	—	0.001	W	
	Timer output	—	—	0.002	W	

NOTE

$AV_{DD}n$ (1.0 V) is estimated to consume 0.05 W (under normal operating conditions and ambient temperature).

4 Clock Input Timing

This section provides the clock input DC and AC electrical characteristics for the MPC8323E.

NOTE

The rise/fall time on QUICC Engine input pins should not exceed 5 ns. This should be enforced especially on clock signals. Rise time refers to signal transitions from 10% to 90% of VCC; fall time refers to transitions from 90% to 10% of VCC.

4.1 DC Electrical Characteristics

Table 7 provides the clock input (CLKIN/PCI_SYNC_IN) DC timing specifications for the MPC8323E.

Table 7. CLKIN DC Electrical Characteristics

Parameter	Condition	Symbol	Min	Max	Unit
Input high voltage	—	V_{IH}	2.7	OV_{DD} + 0.3	V
Input low voltage	—	V_{IL}	–0.3	0.4	V

Table 7. CLKIN DC Electrical Characteristics (continued)

CLKIN input current	$0 V \le V_{IN} \le OV_{DD}$	I_{IN}	—	±5	μA
PCI_SYNC_IN input current	$0 V \le V_{IN} \le 0.5 V$ or $OV_{DD} - 0.5 V \le V_{IN} \le OV_{DD}$	I_{IN}	—	±5	μA
PCI_SYNC_IN input current	$0.5 V \le V_{IN} \le OV_{DD} - 0.5 V$	I_{IN}	—	±50	μA

4.2 AC Electrical Characteristics

The primary clock source for the MPC8323E can be one of two inputs, CLKIN or PCI_CLK, depending on whether the device is configured in PCI host or PCI agent mode. Table 8 provides the clock input (CLKIN/PCI_CLK) AC timing specifications for the MPC8323E.

Table 8. CLKIN AC Timing Specifications

Parameter/Condition	Symbol	Min	Typical	Max	Unit	Notes
CLKIN/PCI_CLK frequency	f_{CLKIN}	25	—	66.67	MHz	1
CLKIN/PCI_CLK cycle time	t_{CLKIN}	15	—	—	ns	—
CLKIN rise and fall time	t_{KH}, t_{KL}	0.6	0.8	4	ns	2
PCI_CLK rise and fall time	t_{PCH}, t_{PCL}	0.6	0.8	1.2	ns	2
CLKIN/PCI_CLK duty cycle	t_{KHK}/t_{CLKIN}	40	—	60	%	3
CLKIN/PCI_CLK jitter	—	—	—	±150	ps	4, 5

Notes:
1. **Caution:** The system, core, security, and QUICC Engine block must not exceed their respective maximum or minimum operating frequencies.
2. Rise and fall times for CLKIN/PCI_CLK are measured at 0.4 and 2.7 V.
3. Timing is guaranteed by design and characterization.
4. This represents the total input jitter—short term and long term—and is guaranteed by design.
5. The CLKIN/PCI_CLK driver's closed loop jitter bandwidth should be < 500 kHz at –20 dB. The bandwidth must be set low to allow cascade-connected PLL-based devices to track CLKIN drivers with the specified jitter.

5 RESET Initialization

This section describes the AC electrical specifications for the reset initialization timing requirements of the MPC8323E. Table 9 provides the reset initialization AC timing specifications for the reset component(s).

Table 9. RESET Initialization Timing Specifications

Parameter/Condition	Min	Max	Unit	Notes
Required assertion time of $\overline{\text{HRESET}}$ or $\overline{\text{SRESET}}$ (input) to activate reset flow	32	—	$t_{PCI\_SYNC\_IN}$	1
Required assertion time of $\overline{\text{PORESET}}$ with stable clock applied to CLKIN when the MPC8323E is in PCI host mode	32	—	t_{CLKIN}	2
Required assertion time of $\overline{\text{PORESET}}$ with stable clock applied to PCI_SYNC_IN when the MPC8323E is in PCI agent mode	32	—	$t_{PCI\_SYNC\_IN}$	1

6.2 DDR1 and DDR2 SDRAM AC Electrical Characteristics

This section provides the AC electrical characteristics for the DDR1 and DDR2 SDRAM interface.

6.2.1 DDR1 and DDR2 SDRAM Input AC Timing Specifications

Table 16 provides the input AC timing specifications for the DDR2 SDRAM (D*n*_GV_{DD}(typ) = 1.8 V).

Table 16. DDR2 SDRAM Input AC Timing Specifications for 1.8-V Interface

At recommended operating conditions with D*n*_GV_{DD} of 1.8 ± 5%.

Parameter	Symbol	Min	Max	Unit	Notes
AC input low voltage	V_{IL}	—	MVREFn_{REF} – 0.25	V	—
AC input high voltage	V_{IH}	MVREFn_{REF} + 0.25	—	V	—

Table 17 provides the input AC timing specifications for the DDR1 SDRAM (D*n*_GV_{DD}(typ) = 2.5 V).

Table 17. DDR1 SDRAM Input AC Timing Specifications for 2.5 V Interface

At recommended operating conditions with D*n*_GV_{DD} of 2.5 ± 5%.

Parameter	Symbol	Min	Max	Unit	Notes
AC input low voltage	V_{IL}	—	MVREFn_{REF} – 0.31	V	—
AC input high voltage	V_{IH}	MVREFn_{REF} + 0.31	—	V	—

Table 18 provides the input AC timing specifications for the DDR1 and DDR2 SDRAM interface.

Table 18. DDR1 and DDR2 SDRAM Input AC Timing Specifications

At recommended operating conditions with D*n*_GV_{DD} of (1.8 or 2.5 V) ± 5%.

Parameter	Symbol	Min	Max	Unit	Notes
Controller skew for MDQS—MDQ/MDM	t_{CISKEW}			ps	1, 2
266 MHz		–750	750		
200 MHz		–1250	1250		

Notes:

1. t_{CISKEW} represents the total amount of skew consumed by the controller between MDQS[n] and any corresponding bit that is captured with MDQS[n]. This should be subtracted from the total timing budget.
2. The amount of skew that can be tolerated from MDQS to a corresponding MDQ signal is called t_{DISKEW}. This can be determined by the following equation: $t_{DISKEW} = \pm(T/4 - abs(t_{CISKEW}))$ where T is the clock period and $abs(t_{CISKEW})$ is the absolute value of t_{CISKEW}.

(management data clock). The MII and RMII are defined for 3.3 V. The electrical characteristics for MDIO and MDC are specified in Section 8.3, "Ethernet Management Interface Electrical Characteristics."

8.1.1 DC Electrical Characteristics

All MII and RMII drivers and receivers comply with the DC parametric attributes specified in Table 22.

Table 22. MII and RMII DC Electrical Characteristics

Parameter	Symbol	Conditions		Min	Max	Unit
Supply voltage 3.3 V	OV_{DD}	—		2.97	3.63	V
Output high voltage	V_{OH}	I_{OH} = –4.0 mA	OV_{DD} = Min	2.40	OV_{DD} + 0.3	V
Output low voltage	V_{OL}	I_{OL} = 4.0 mA	OV_{DD} = Min	GND	0.50	V
Input high voltage	V_{IH}	—	—	2.0	OV_{DD} + 0.3	V
Input low voltage	V_{IL}	—	—	–0.3	0.90	V
Input current	I_{IN}	$0 V \le V_{IN} \le OV_{DD}$		—	±5	μA

8.2 MII and RMII AC Timing Specifications

The AC timing specifications for MII and RMII are presented in this section.

8.2.1 MII AC Timing Specifications

This section describes the MII transmit and receive AC timing specifications.

8.2.1.1 MII Transmit AC Timing Specifications

Table 23 provides the MII transmit AC timing specifications.

Table 23. MII Transmit AC Timing Specifications

At recommended operating conditions with OV_{DD} of 3.3 V ± 10%.

Parameter/Condition	Symbol[1]	Min	Typical	Max	Unit
TX_CLK clock period 10 Mbps	t_{MTX}	—	400	—	ns
TX_CLK clock period 100 Mbps	t_{MTX}	—	40	—	ns
TX_CLK duty cycle	t_{MTXH}/t_{MTX}	35	—	65	%
TX_CLK to MII data TXD[3:0], TX_ER, TX_EN delay	t_{MTKHDX}	1	5	15	ns
TX_CLK data clock rise time	t_{MTXR}	1.0	—	4.0	ns

Table 23. MII Transmit AC Timing Specifications (continued)

At recommended operating conditions with OV_{DD} of 3.3 V ± 10%.

Parameter/Condition	Symbol[1]	Min	Typical	Max	Unit
TX_CLK data clock fall time	t_{MTXF}	1.0	—	4.0	ns

Note:

1. The symbols used for timing specifications follow the pattern of $t_{\text{(first two letters of functional block)(signal)(state)(reference)(state)}}$ for inputs and $t_{\text{(first two letters of functional block)(reference)(state)(signal)(state)}}$ for outputs. For example, t_{MTKHDX} symbolizes MII transmit timing (MT) for the time t_{MTX} clock reference (K) going high (H) until data outputs (D) are invalid (X). Note that, in general, the clock reference symbol representation is based on two to three letters representing the clock of a particular functional. For example, the subscript of t_{MTX} represents the MII(M) transmit (TX) clock. For rise and fall times, the latter convention is used with the appropriate letter: R (rise) or F (fall).

Figure 7 shows the MII transmit AC timing diagram.

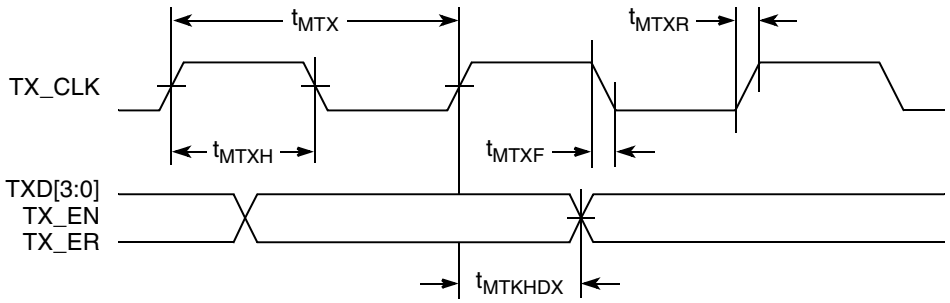


Figure 7. MII Transmit AC Timing Diagram

8.2.1.2 MII Receive AC Timing Specifications

Table 24 provides the MII receive AC timing specifications.

Table 24. MII Receive AC Timing Specifications

At recommended operating conditions with OV_{DD} of 3.3 V ± 10%.

Parameter/Condition	Symbol[1]	Min	Typical	Max	Unit
RX_CLK clock period 10 Mbps	t_{MRX}	—	400	—	ns
RX_CLK clock period 100 Mbps	t_{MRX}	—	40	—	ns
RX_CLK duty cycle	t_{MRXH}/t_{MRX}	35	—	65	%
RXD[3:0], RX_DV, RX_ER setup time to RX_CLK	t_{MRDVKH}	10.0	—	—	ns
RXD[3:0], RX_DV, RX_ER hold time to RX_CLK	t_{MRDXKH}	10.0	—	—	ns
RX_CLK clock rise time	t_{MRXR}	1.0	—	4.0	ns

Table 24. MII Receive AC Timing Specifications (continued)

At recommended operating conditions with OV_{DD} of 3.3 V ± 10%.

Parameter/Condition	Symbol[1]	Min	Typical	Max	Unit
RX_CLK clock fall time	t_{MRXF}	1.0	—	4.0	ns

Note:

1. The symbols used for timing specifications follow the pattern of $t_{\text{(first two letters of functional block)(signal)(state)(reference)(state)}}$ for inputs and $t_{\text{(first two letters of functional block)(reference)(state)(signal)(state)}}$ for outputs. For example, t_{MRDVKH} symbolizes MII receive timing (MR) with respect to the time data input signals (D) reach the valid state (V) relative to the t_{MRX} clock reference (K) going to the high (H) state or setup time. Also, t_{MRDXKL} symbolizes MII receive timing (GR) with respect to the time data input signals (D) went invalid (X) relative to the t_{MRX} clock reference (K) going to the low (L) state or hold time. Note that, in general, the clock reference symbol representation is based on three letters representing the clock of a particular functional. For example, the subscript of t_{MRX} represents the MII (M) receive (RX) clock. For rise and fall times, the latter convention is used with the appropriate letter: R (rise) or F (fall).

Figure 8 provides the AC test load.

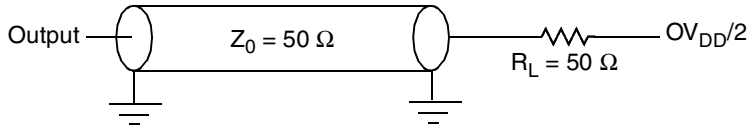


Figure 8. AC Test Load

Figure 9 shows the MII receive AC timing diagram.

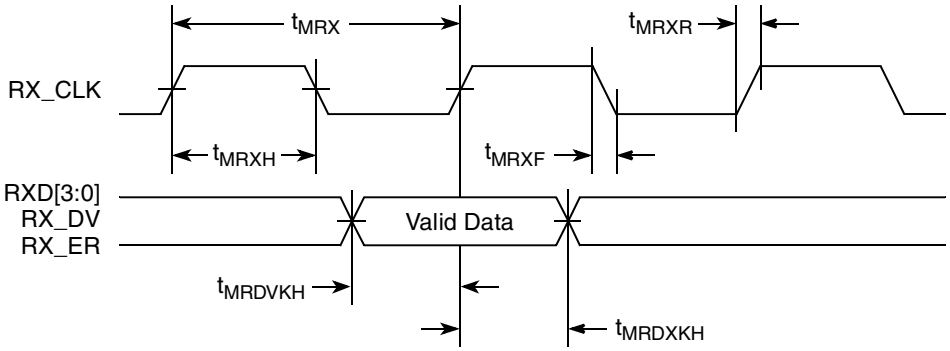


Figure 9. MII Receive AC Timing Diagram

8.2.2 RMII AC Timing Specifications

This section describes the RMII transmit and receive AC timing specifications.

Figure 28 provides the AC test load for the timers.

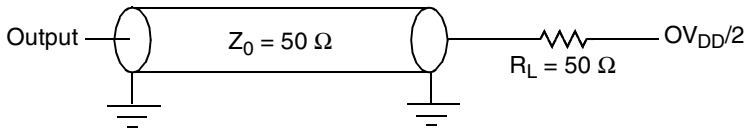


Figure 28. Timers AC Test Load

14 GPIO

This section describes the DC and AC electrical specifications for the GPIO of the MPC8323E.

14.1 GPIO DC Electrical Characteristics

Table 11 provides the DC electrical characteristics for the MPC8323E GPIO.

Table 40. GPIO DC Electrical Characteristics

Characteristic	Symbol	Condition	Min	Max	Unit	Notes
Output high voltage	V_{OH}	I_{OH} = –6.0 mA	2.4	—	V	1
Output low voltage	V_{OL}	I_{OL} = 6.0 mA	—	0.5	V	1
Output low voltage	V_{OL}	I_{OL} = 3.2 mA	—	0.4	V	1
Input high voltage	V_{IH}	—	2.0	OV_{DD} + 0.3	V	1
Input low voltage	V_{IL}	—	–0.3	0.8	V	—
Input current	I_{IN}	0 V ≤ V_{IN} ≤ OV_{DD}	—	±5	μA	—

Note:
1. This specification applies when operating from 3.3-V supply.

14.2 GPIO AC Timing Specifications

Table 41 provides the GPIO input and output AC timing specifications.

Table 41. GPIO Input AC Timing Specifications[1]

Characteristic	Symbol[2]	Min	Unit
GPIO inputs—minimum pulse width	t_{PIWID}	20	ns

Notes:
1. Input specifications are measured from the 50% level of the signal to the 50% level of the rising edge of CLKIN. Timings are measured at the pin.
2. GPIO inputs and outputs are asynchronous to any visible clock. GPIO outputs should be synchronized before use by any external synchronous logic. GPIO inputs are required to be valid for at least t_{PIWID} ns to ensure proper operation.

Figure 29 provides the AC test load for the GPIO.

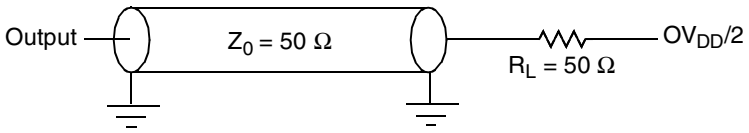


Figure 29. GPIO AC Test Load

15 IPIC

This section describes the DC and AC electrical specifications for the external interrupt pins of the MPC8323E.

15.1 IPIC DC Electrical Characteristics

Table 42 provides the DC electrical characteristics for the external interrupt pins of the MPC8323E.

Table 42. IPIC DC Electrical Characteristics[1,2]

Characteristic	Symbol	Condition	Min	Max	Unit
Input high voltage	V_{IH}	—	2.0	OV_{DD} + 0.3	V
Input low voltage	V_{IL}	—	–0.3	0.8	V
Input current	I_{IN}	—	—	±5	μA
Output low voltage	V_{OL}	I_{OL} = 6.0 mA	—	0.5	V
Output low voltage	V_{OL}	I_{OL} = 3.2 mA	—	0.4	V

Notes:
1. This table applies for pins $\overline{\text{IRQ}}$[0:7], $\overline{\text{IRQ\_OUT}}$, $\overline{\text{MCP\_OUT}}$, and CE ports Interrupts.
2. $\overline{\text{IRQ\_OUT}}$ and $\overline{\text{MCP\_OUT}}$ are open drain pins, thus V_{OH} is not relevant for those pins.

15.2 IPIC AC Timing Specifications

Table 43 provides the IPIC input and output AC timing specifications.

Table 43. IPIC Input AC Timing Specifications[1]

Characteristic	Symbol[2]	Min	Unit
IPIC inputs—minimum pulse width	t_{PIWID}	20	ns

Notes:
1. Input specifications are measured from the 50% level of the signal to the 50% level of the rising edge of CLKIN. Timings are measured at the pin.
2. IPIC inputs and outputs are asynchronous to any visible clock. IPIC outputs should be synchronized before use by any external synchronous logic. IPIC inputs are required to be valid for at least t_{PIWID} ns to ensure proper operation when working in edge triggered mode.

16 SPI

This section describes the DC and AC electrical specifications for the SPI of the MPC8323E.

16.1 SPI DC Electrical Characteristics

Table 44 provides the DC electrical characteristics for the MPC8323E SPI.

Table 44. SPI DC Electrical Characteristics

Characteristic	Symbol	Condition	Min	Max	Unit
Output high voltage	V_{OH}	I_{OH} = –6.0 mA	2.4	—	V
Output low voltage	V_{OL}	I_{OL} = 6.0 mA	—	0.5	V
Output low voltage	V_{OL}	I_{OL} = 3.2 mA	—	0.4	V
Input high voltage	V_{IH}	—	2.0	OV_{DD} + 0.3	V
Input low voltage	V_{IL}	—	–0.3	0.8	V
Input current	I_{IN}	0 V ≤ V_{IN} ≤ OV_{DD}	—	±5	μA

16.2 SPI AC Timing Specifications

Table 45 and provide the SPI input and output AC timing specifications.

Table 45. SPI AC Timing Specifications[1]

Characteristic	Symbol[2]	Min	Max	Unit
SPI outputs—Master mode (internal clock) delay	t_{NIKHOV}	0.5	6	ns
SPI outputs—Slave mode (external clock) delay	t_{NEKHOV}	2	8	ns
SPI inputs—Master mode (internal clock) input setup time	t_{NIIVKH}	6	—	ns
SPI inputs—Master mode (internal clock) input hold time	t_{NIIXKH}	0	—	ns
SPI inputs—Slave mode (external clock) input setup time	t_{NEIVKH}	4	—	ns
SPI inputs—Slave mode (external clock) input hold time	t_{NEIXKH}	2	—	ns

Notes:
1. Output specifications are measured from the 50% level of the rising edge of CLKIN to the 50% level of the signal. Timings are measured at the pin.
2. The symbols used for timing specifications follow the pattern of $t_{\text{(first two letters of functional block)(signal)(state)(reference)(state)}}$ for inputs and $t_{\text{(first two letters of functional block)(reference)(state)(signal)(state)}}$ for outputs. For example, t_{NIKHOV} symbolizes the NMSI outputs internal timing (NI) for the time t_{SPI} memory clock reference (K) goes from the high state (H) until outputs (O) are valid (V).

Figure 30 provides the AC test load for the SPI.

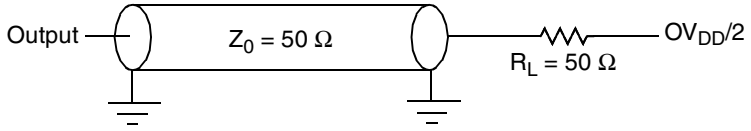


Figure 30. SPI AC Test Load

Table 46. TDM/SI DC Electrical Characteristics (continued)

Characteristic	Symbol	Condition	Min	Max	Unit
Input low voltage	V_{IL}	—	–0.3	0.8	V
Input current	I_{IN}	$0 V \le V_{IN} \le OV_{DD}$	—	±5	μA

17.2 TDM/SI AC Timing Specifications

Table 47 provides the TDM/SI input and output AC timing specifications.

Table 47. TDM/SI AC Timing Specifications[1]

Characteristic	Symbol[2]	Min	Max	Unit
TDM/SI outputs—External clock delay	t_{SEKHOV}	2	12	ns
TDM/SI outputs—External clock High Impedance	t_{SEKHOX}	2	10	ns
TDM/SI inputs—External clock input setup time	t_{SEIVKH}	5	—	ns
TDM/SI inputs—External clock input hold time	t_{SEIXKH}	2	—	ns

Notes:
1. Output specifications are measured from the 50% level of the rising edge of CLKIN to the 50% level of the signal. Timings are measured at the pin.
2. The symbols used for timing specifications follow the pattern of $t_{\text{(first two letters of functional block)(signal)(state)(reference)(state)}}$ for inputs and $t_{\text{(first two letters of functional block)(reference)(state)(signal)(state)}}$ for outputs. For example, t_{SEKHOX} symbolizes the TDM/SI outputs external timing (SE) for the time $t_{TDM/SI}$ memory clock reference (K) goes from the high state (H) until outputs (O) are invalid (X).

Figure 33 provides the AC test load for the TDM/SI.

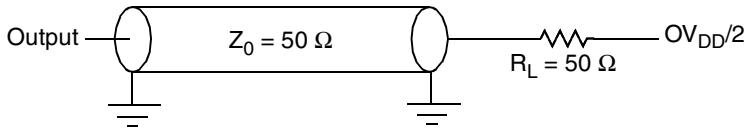
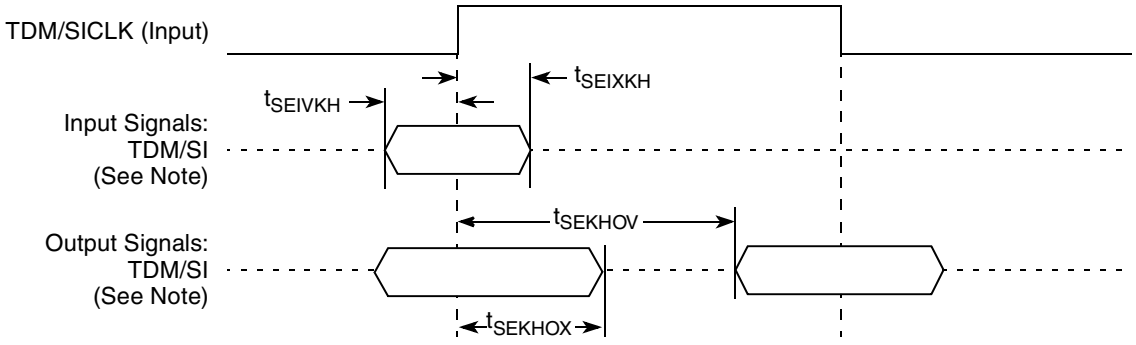


Figure 33. TDM/SI AC Test Load

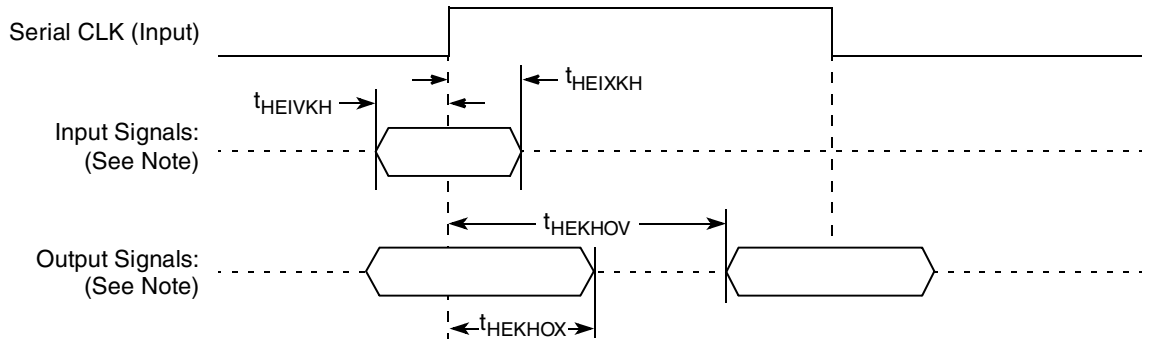
Figure 34 represents the AC timing from Table 47. Note that although the specifications generally reference the rising edge of the clock, these AC timing diagrams also apply when the falling edge is the active edge.



Note: The clock edge is selectable on TDM/SI.

Figure 34. TDM/SI AC Timing (External Clock) Diagram

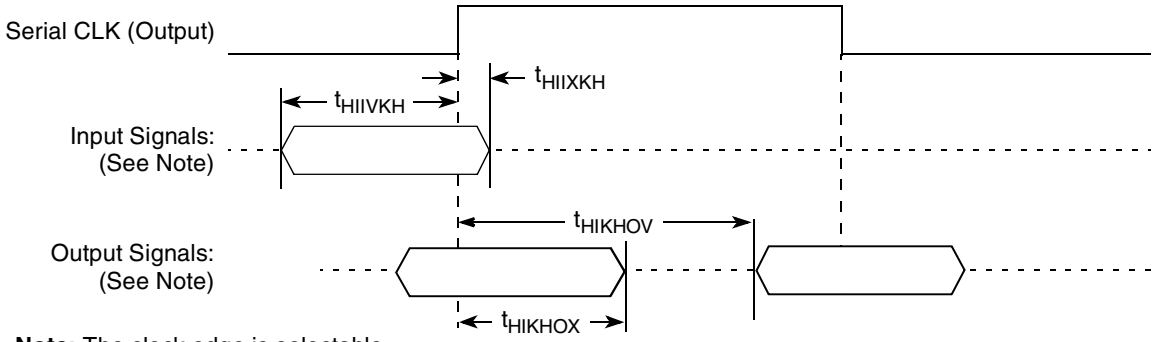
Figure 39 shows the timing with external clock.



Note: The clock edge is selectable.

Figure 39. AC Timing (External Clock) Diagram

Figure 40 shows the timing with internal clock.



Note: The clock edge is selectable.

Figure 40. AC Timing (Internal Clock) Diagram

Table 55. MPC8323E PBGA Pinout Listing (continued)

Signal	Package Pin Number	Pin Type	Power Supply	Notes
Power and Ground Supplies				
$AV_{DD}1$	P3	I	$AV_{DD}1$	—
$AV_{DD}2$	AA1	I	$AV_{DD}2$	—
$AV_{DD}3$	AB15	I	$AV_{DD}3$	—
$AV_{DD}4$	C24	I	$AV_{DD}4$	—
MVREF1	AB8	I	DDR reference voltage	—
MVREF2	AB17	I	DDR reference voltage	—
PCI				
$\overline{\text{PCI\_INTA}}$ /$\overline{\text{IRQ\_OUT}}$	AF2	O	OV_{DD}	2
$\overline{\text{PCI\_RESET\_OUT}}$	AE2	O	OV_{DD}	—
PCI_AD0/MSRCID0 (DDR ID)	L1	IO	OV_{DD}	—
PCI_AD1/MSRCID1 (DDR ID)	L2	IO	OV_{DD}	—
PCI_AD2/MSRCID2 (DDR ID)	M1	IO	OV_{DD}	—
PCI_AD3/MSRCID3 (DDR ID)	M2	IO	OV_{DD}	—
PCI_AD4/MSRCID4 (DDR ID)	L3	IO	OV_{DD}	—
PCI_AD5/MDVAL (DDR ID)	N1	IO	OV_{DD}	—
PCI_AD6	N2	IO	OV_{DD}	—
PCI_AD7	M3	IO	OV_{DD}	—
PCI_AD8	P1	IO	OV_{DD}	—
PCI_AD9	R1	IO	OV_{DD}	—
PCI_AD10	N3	IO	OV_{DD}	—
PCI_AD11	N4	IO	OV_{DD}	—
PCI_AD12	T1	IO	OV_{DD}	—
PCI_AD13	R2	IO	OV_{DD}	—
PCI_AD14/ECID_TMODE_IN	T2	IO	OV_{DD}	—
PCI_AD15	U1	IO	OV_{DD}	—
PCI_AD16	Y2	IO	OV_{DD}	—
PCI_AD17	Y1	IO	OV_{DD}	—
PCI_AD18	AA2	IO	OV_{DD}	—
PCI_AD19	AB1	IO	OV_{DD}	—

Table 55. MPC8323E PBGA Pinout Listing (continued)

Signal	Package Pin Number	Pin Type	Power Supply	Notes
GPIO_PA26/Enet2_RX_ER/SER2_CD/TDMB_REQ/ LA10 (LBIU)	E26	IO	OV_{DD}	—
GPIO_PA27/Enet2_TX_ER/TDMB_CLKO/LA11 (LBIU)	F25	IO	OV_{DD}	—
GPIO_PA28/Enet2_RX_DV/SER2_CTS/ TDMB_RSYNC/LA12 (LBIU)	E25	IO	OV_{DD}	—
GPIO_PA29/Enet2_COL/RXD[4]/SER2_RXD[4]/ TDMB_STROBE/LA13 (LBIU)	J25	IO	OV_{DD}	—
GPIO_PA30/Enet2_TX_EN/SER2_RTS/ TDMB_TSYNC/LA14 (LBIU)	F26	IO	OV_{DD}	—
GPIO_PA31/Enet2_CRS/SDET LA15 (LBIU)	J26	IO	OV_{DD}	—
GPIO_PB0/Enet3_TXD[0]/SER3_TXD[0]/ TDMC_TXD[0]	A13	IO	OV_{DD}	—
GPIO_PB1/Enet3_TXD[1]/SER3_TXD[1]/ TDMC_TXD[1]	B13	IO	OV_{DD}	—
GPIO_PB2/Enet3_TXD[2]/SER3_TXD[2]/ TDMC_TXD[2]	A14	IO	OV_{DD}	—
GPIO_PB3/Enet3_TXD[3]/SER3_TXD[3]/ TDMC_TXD[3]	B14	IO	OV_{DD}	—
GPIO_PB4/Enet3_RXD[0]/SER3_RXD[0]/ TDMC_RXD[0]	B8	IO	OV_{DD}	—
GPIO_PB5/Enet3_RXD[1]/SER3_RXD[1]/ TDMC_RXD[1]	A8	IO	OV_{DD}	—
GPIO_PB6/Enet3_RXD[2]/SER3_RXD[2]/ TDMC_RXD[2]	A9	IO	OV_{DD}	—
GPIO_PB7/Enet3_RXD[3]/SER3_RXD[3]/ TDMC_RXD[3]	B9	IO	OV_{DD}	—
GPIO_PB8/Enet3_RX_ER/SER3_CD/TDMC_REQ	A11	IO	OV_{DD}	—
GPIO_PB9/Enet3_TX_ER/TDMC_CLKO	B11	IO	OV_{DD}	—
GPIO_PB10/Enet3_RX_DV/SER3_CTS/ TDMC_RSYNC	A10	IO	OV_{DD}	—
GPIO_PB11/Enet3_COL/RXD[4]/SER3_RXD[4]/ TDMC_STROBE	A15	IO	OV_{DD}	—
GPIO_PB12/Enet3_TX_EN/SER3_RTS/ TDMC_TSYNC	B12	IO	OV_{DD}	—
GPIO_PB13/Enet3_CRS/SDET	B15	IO	OV_{DD}	—
GPIO_PB14/CLK12	D9	IO	OV_{DD}	—
GPIO_PB15 UPC1_TxADDR[4]	D14	IO	OV_{DD}	—
GPIO_PB16 UPC1_RxADDR[4]	B16	IO	OV_{DD}	—

Table 55. MPC8323E PBGA Pinout Listing (continued)

Signal	Package Pin Number	Pin Type	Power Supply	Notes
GPIO_PB17/BRGO1/CE_EXT_REQ1	D10	IO	OV_{DD}	—
GPIO_PB18/Enet4_TXD[0]/SER4_TXD[0]/ TDMD_TXD[0]	C10	IO	OV_{DD}	—
GPIO_PB19/Enet4_TXD[1]/SER4_TXD[1]/ TDMD_TXD[1]	C9	IO	OV_{DD}	—
GPIO_PB20/Enet4_TXD[2]/SER4_TXD[2]/ TDMD_TXD[2]	D8	IO	OV_{DD}	—
GPIO_PB21/Enet4_TXD[3]/SER4_TXD[3]/ TDMD_TXD[3]	C8	IO	OV_{DD}	—
GPIO_PB22/Enet4_RXD[0]/SER4_RXD[0]/ TDMD_RXD[0]	C15	IO	OV_{DD}	—
GPIO_PB23/Enet4_RXD[1]/SER4_RXD[1]/ TDMD_RXD[1]	C14	IO	OV_{DD}	—
GPIO_PB24/Enet4_RXD[2]/SER4_RXD[2]/ TDMD_RXD[2]	D13	IO	OV_{DD}	—
GPIO_PB25/Enet4_RXD[3]/SER4_RXD[3]/ TDMD_RXD[3]	C13	IO	OV_{DD}	—
GPIO_PB26/Enet4_RX_ER/SER4_CD/TDMD_REQ	C12	IO	OV_{DD}	—
GPIO_PB27/Enet4_TX_ER/TDMD_CLKO	D11	IO	OV_{DD}	—
GPIO_PB28/Enet4_RX_DV/SER4_CTS/ TDMD_RSYNC	D12	IO	OV_{DD}	—
GPIO_PB29/Enet4_COL/RXD[4]/SER4_RXD[4]/ TDMD_STROBE	D7	IO	OV_{DD}	—
GPIO_PB30/Enet4_TX_EN/SER4_RTS/ TDMD_TSYNC	C11	IO	OV_{DD}	—
GPIO_PB31/Enet4_CRS/SDET	C7	IO	OV_{DD}	—
GPIO_PC0/UPC1_TxDATA[0]/SER5_TXD[0]	A18	IO	OV_{DD}	—
GPIO_PC1/UPC1_TxDATA[1]/SER5_TXD[1]	A19	IO	OV_{DD}	—
GPIO_PC2/UPC1_TxDATA[2]/SER5_TXD[2]	B18	IO	OV_{DD}	—
GPIO_PC3/UPC1_TxDATA[3]/SER5_TXD[3]	B19	IO	OV_{DD}	—
GPIO_PC4/UPC1_TxDATA[4]	A24	IO	OV_{DD}	—
GPIO_PC5/UPC1_TxDATA[5]	B24	IO	OV_{DD}	—
GPIO_PC6/UPC1_TxDATA[6]	A23	IO	OV_{DD}	—
GPIO_PC7/UPC1_TxDATA[7]	B26	IO	OV_{DD}	—
GPIO_PC8/UPC1_RxDATA[0]/SER5_RXD[0]	A21	IO	OV_{DD}	—
GPIO_PC9/UPC1_RxDATA[1]/SER5_RXD[1]	B20	IO	OV_{DD}	—

Table 55. MPC8323E PBGA Pinout Listing (continued)

Signal	Package Pin Number	Pin Type	Power Supply	Notes
GPIO_PC10/UPC1_RxDATA[2]/SER5_RXD[2]	B21	IO	OV_{DD}	—
GPIO_PC11/UPC1_RxDATA[3]/SER5_RXD[3]	A20	IO	OV_{DD}	—
GPIO_PC12/UPC1_RxDATA[4]	D19	IO	OV_{DD}	—
GPIO_PC13/UPC1_RxDATA[5]/LSRCID0	C18	IO	OV_{DD}	—
GPIO_PC14/UPC1_RxDATA[6]/LSRCID1	D18	IO	OV_{DD}	—
GPIO_PC15/UPC1_RxDATA[7]/LSRCID2	A25	IO	OV_{DD}	—
GPIO_PC16/UPC1_TxADDR[0]	C21	IO	OV_{DD}	—
GPIO_PC17/UPC1_TxADDR[1]/LSRCID3	D22	IO	OV_{DD}	—
GPIO_PC18/UPC1_TxADDR[2]/LSRCID4	C23	IO	OV_{DD}	—
GPIO_PC19/UPC1_TxADDR[3]/LDVAL	D23	IO	OV_{DD}	—
GPIO_PC20/UPC1_RxADDR[0]	C17	IO	OV_{DD}	—
GPIO_PC21/UPC1_RxADDR[1]	D17	IO	OV_{DD}	—
GPIO_PC22/UPC1_RxADDR[2]	C16	IO	OV_{DD}	—
GPIO_PC23/UPC1_RxADDR[3]	D16	IO	OV_{DD}	—
GPIO_PC24/UPC1_RxSOC/SER5_CD	A16	IO	OV_{DD}	—
GPIO_PC25/UPC1_RxCLAV	D20	IO	OV_{DD}	—
GPIO_PC26/UPC1_RxPRTY/CE_EXT_REQ2	E23	IO	OV_{DD}	—
GPIO_PC27/UPC1_RxEN	B17	IO	OV_{DD}	—
GPIO_PC28/UPC1_TxSOC	B22	IO	OV_{DD}	—
GPIO_PC29/UPC1_TxCLAV/SER5_CTS	A17	IO	OV_{DD}	—
GPIO_PC30/UPC1_TxPRTY	A22	IO	OV_{DD}	—
GPIO_PC31/UPC1_TxEN/SER5_RTS	C20	IO	OV_{DD}	—
GPIO_PD0/SPIMOSI	A2	IO	OV_{DD}	—
GPIO_PD1/SPIMISO	B2	IO	OV_{DD}	—
GPIO_PD2/SPICLK	B3	IO	OV_{DD}	—
GPIO_PD3/SPISEL	A3	IO	OV_{DD}	—
GPIO_PD4/SPI_MDIO/CE_MUX_MDIO	A4	IO	OV_{DD}	—
GPIO_PD5/SPI_MDC/CE_MUX_MDC	B4	IO	OV_{DD}	—
GPIO_PD6/CLK8/BRGO16/CE_EXT_REQ3	F24	IO	OV_{DD}	—
GPIO_PD7/GTM1_TIN1/GTM2_TIN2/CLK5	G24	IO	OV_{DD}	—
GPIO_PD8/$\overline{\text{GTM1\_TGATE1}}$/$\overline{\text{GTM2\_TGATE2}}$/CLK6	H24	IO	OV_{DD}	—
GPIO_PD9/$\overline{\text{GTM1\_TOUT1}}$	D24	IO	OV_{DD}	—

22 Clocking

Figure 43 shows the internal distribution of clocks within the MPC8323E.

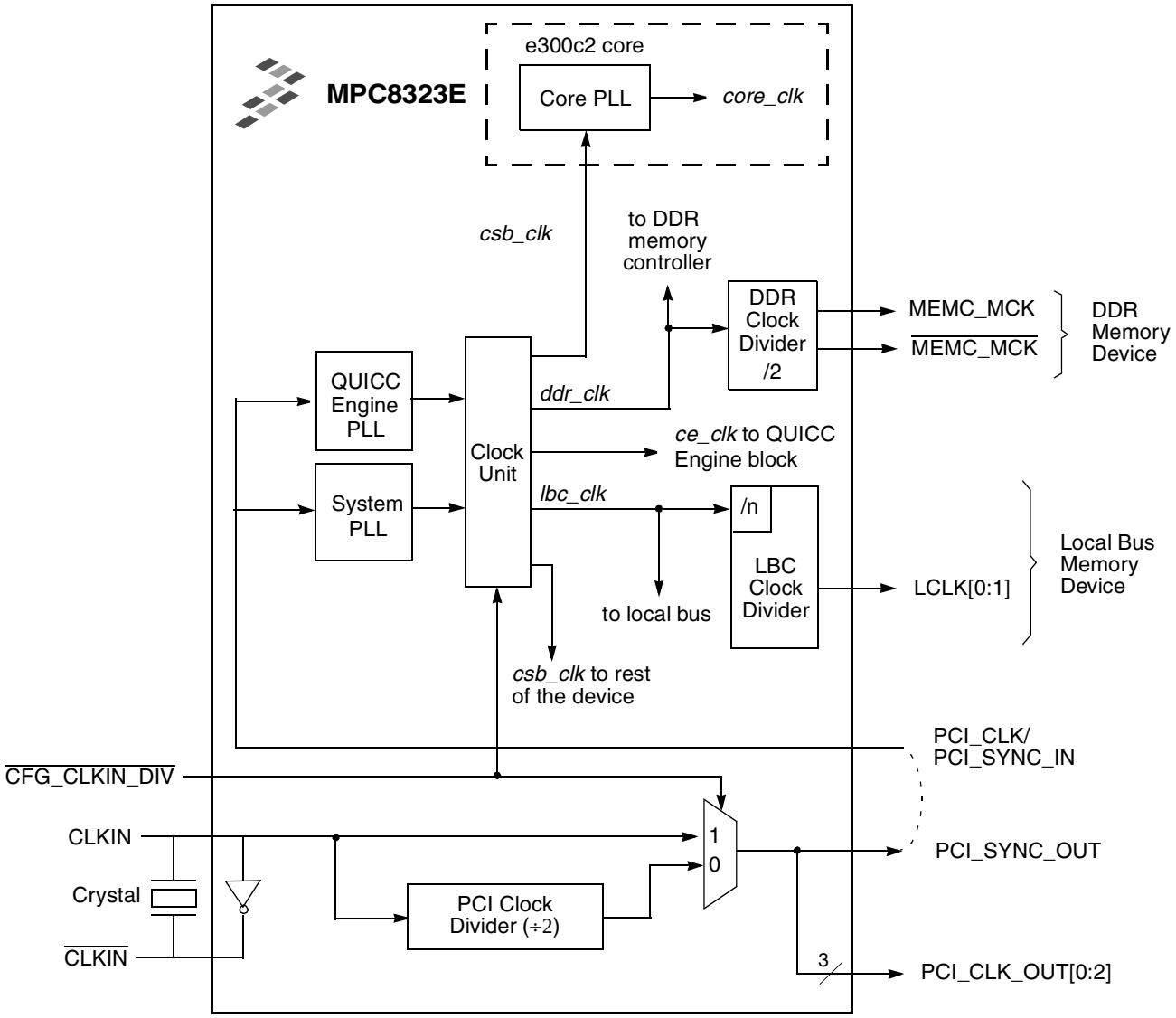


Figure 43. MPC8323E Clock Subsystem

The primary clock source for the MPC8323E can be one of two inputs, CLKIN or PCI_CLK, depending on whether the device is configured in PCI host or PCI agent mode, respectively.

The *ce_clk* frequency is determined by the QUICC Engine PLL multiplication factor (RCWL[CEPMF) and the QUICC Engine PLL division factor (RCWL[CEPDF]) according to the following equation:

When CLKIN is the primary input clock,

ce_clk = (primary clock input × CEPMF) ÷ (1 + CEPDF)

When PCI_CLK is the primary input clock,

ce_clk = [primary clock input × CEPMF × (1 + ~CFG_CLKIN_DIV)] ÷ (1 + CEPDF)

See the "QUICC Engine PLL Multiplication Factor" section and the "QUICC Engine PLL Division Factor" section in the *MPC8323E PowerQUICC II Pro Communications Processor Reference Manual* for more information.

The DDR SDRAM memory controller operates with a frequency equal to twice the frequency of *csb_clk*. Note that *ddr_clk* is not the external memory bus frequency; *ddr_clk* passes through the DDR clock divider (÷2) to create the differential DDR memory bus clock outputs (MCK and $\overline{\text{MCK}}$). However, the data rate is the same frequency as *ddr_clk*.

The local bus memory controller operates with a frequency equal to the frequency of *csb_clk*. Note that *lbc_clk* is not the external local bus frequency; *lbc_clk* passes through the LBC clock divider to create the external local bus clock outputs (LSYNC_OUT and LCLK[0:2]). The LBC clock divider ratio is controlled by LCRR[CLKDIV]. See the "LBC Bus Clock and Clock Ratios" section in the *MPC8323E PowerQUICC II Pro Communications Processor Reference Manual* for more information.

In addition, some of the internal units may be required to be shut off or operate at lower frequency than the *csb_clk* frequency. These units have a default clock ratio that can be configured by a memory mapped register after the device comes out of reset. Table 56 specifies which units have a configurable clock frequency. Refer to the "System Clock Control Register (SCCR)" section in the *MPC8323E PowerQUICC II Pro Communications Processor Reference Manual* for a detailed description.

Table 56. Configurable Clock Units

Unit	Default Frequency	Options
Security core, I2C, SAP, TPR	*csb_clk*	Off, *csb_clk*/2, *csb_clk*/3
PCI and DMA complex	*csb_clk*	Off, *csb_clk*

NOTE

Setting the clock ratio of these units must be performed prior to any access to them.

Table 57 provides the operating frequencies for the 8323E PBGA under recommended operating conditions (see Table 2).

Table 57. Operating Frequencies for PBGA

Characteristic[1]	Max Operating Frequency	Unit
e300 core frequency (*core_clk*)	333	MHz
Coherent system bus frequency (*csb_clk*)	133	MHz
QUICC Engine frequency (*ce_clk*)	200	MHz

Table 64. Package Thermal Characteristics for PBGA (continued)

Characteristic	Board type	Symbol	Value	Unit	Notes
Junction-to-package top	Natural convection	Ψ_{JT}	2	°C/W	6

Notes:
1. Junction temperature is a function of die size, on-chip power dissipation, package thermal resistance, mounting site (board) temperature, ambient temperature, air flow, power dissipation of other components on the board, and board thermal resistance.
2. Per JEDEC JESD51-2 with the single layer board horizontal. Board meets JESD51-9 specification.
3. Per JEDEC JESD51-6 with the board horizontal.
4. Thermal resistance between the die and the printed-circuit board per JEDEC JESD51-8. Board temperature is measured on the top surface of the board near the package.
5. Thermal resistance between the die and the case top surface as measured by the cold plate method (MIL SPEC-883 Method 1012.1).
6. Thermal characterization parameter indicating the temperature difference between package top and the junction temperature per JEDEC JESD51-2. When Greek letters are not available, the thermal characterization parameter is written as Psi-JT.

23.2 Thermal Management Information

For the following sections, $P_D = (V_{DD} \times I_{DD}) + P_{I/O}$, where $P_{I/O}$ is the power dissipation of the I/O drivers.

23.2.1 Estimation of Junction Temperature with Junction-to-Ambient Thermal Resistance

An estimation of the chip junction temperature, T_J, can be obtained from the equation:

$$T_J = T_A + (R_{\theta JA} \times P_D)$$

where:

T_J = junction temperature (°C)

T_A = ambient temperature for the package (°C)

$R_{\theta JA}$ = junction-to-ambient thermal resistance (°C/W)

P_D = power dissipation in the package (W)

The junction-to-ambient thermal resistance is an industry standard value that provides a quick and easy estimation of thermal performance. As a general statement, the value obtained on a single layer board is appropriate for a tightly packed printed-circuit board. The value obtained on the board with the internal planes is usually appropriate if the board has low power dissipation and the components are well separated. Test cases have demonstrated that errors of a factor of two (in the quantity $T_J - T_A$) are possible.

23.2.2 Estimation of Junction Temperature with Junction-to-Board Thermal Resistance

The thermal performance of a device cannot be adequately predicted from the junction-to-ambient thermal resistance. The thermal performance of any component is strongly dependent on the power dissipation of surrounding components. In addition, the ambient temperature varies widely within the application. For many natural convection and especially closed box applications, the board temperature at the perimeter

where:

$R_{\theta JA}$ = junction-to-ambient thermal resistance (°C/W)

$R_{\theta JC}$ = junction-to-case thermal resistance (°C/W)

$R_{\theta CA}$ = case-to-ambient thermal resistance (°C/W)

$R_{\theta JC}$ is device related and cannot be influenced by the user. The user controls the thermal environment to change the case-to-ambient thermal resistance, $R_{\theta CA}$. For instance, the user can change the size of the heat sink, the air flow around the device, the interface material, the mounting arrangement on printed-circuit board, or change the thermal dissipation on the printed-circuit board surrounding the device.

To illustrate the thermal performance of the devices with heat sinks, the thermal performance has been simulated with a few commercially available heat sinks. The heat sink choice is determined by the application environment (temperature, air flow, adjacent component power dissipation) and the physical space available. Because there is not a standard application environment, a standard heat sink is not required.

Accurate thermal design requires thermal modeling of the application environment using computational fluid dynamics software which can model both the conduction cooling and the convection cooling of the air moving through the application. Simplified thermal models of the packages can be assembled using the junction-to-case and junction-to-board thermal resistances listed in the thermal resistance table. More detailed thermal models can be made available on request.

Heat sink vendors include the following list:

Aavid Thermalloy 603-224-9988
80 Commercial St.
Concord, NH 03301
Internet: www.aavidthermalloy.com

Alpha Novatech 408-567-8082
473 Sapena Ct. #12
Santa Clara, CA 95054
Internet: www.alphanovatech.com

International Electronic Research Corporation (IERC) 818-842-7277
413 North Moss St.
Burbank, CA 91502
Internet: www.ctscorp.com

Millennium Electronics (MEI) 408-436-8770
Loroco Sites
671 East Brokaw Road
San Jose, CA 95112
Internet: www.mei-thermal.com

Tyco Electronics 800-522-2800
Chip Coolers™
P.O. Box 3668
Harrisburg, PA 17105-3668
Internet: www.chipcoolers.com